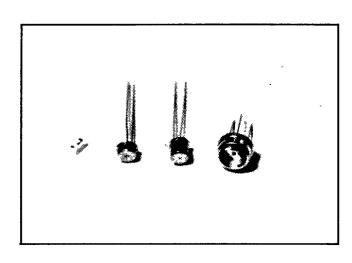
Photodiodes C30618, C30619, C30641, C30642

DATA SHEET

Large Area Planar PIN InGaAs Photodiodes



- Large areas with uniform responsivity (0.10 to 3.14 mm²)
- Spectral response range 1100 to 1700 nm
- High responsivity
- Low capacitance
- Fast response time
- Low dark current and noise
- Available in a variety of convenient packages

RCA's new low capacitance, high speed InGaAs photodetectors utilize the latest passivation and contact technologies to provide lower dark current and noise, with negligible series resistance. 200°C purging, extended lifetest, and periodic qualification programs assure high quality, reliable devices ideally suited for today's demanding electro-optics and communications industries.

Absolute Maximum Ratings 1

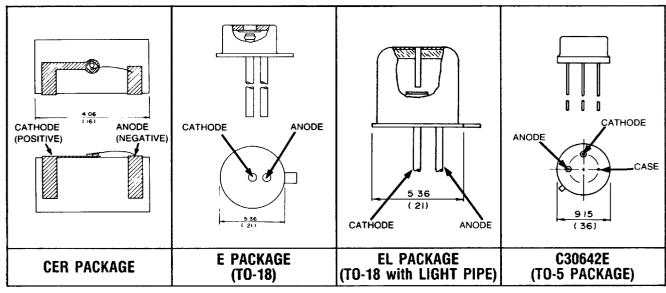
			C30618		C30619		C3	0641	C3	1 15 11000	
	Sym.	Pkg	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	UNITS
Forward Current	I _F	(All)		25		50		100		200	mA
Ambient Temp.: Storage	T _{STG}			,				10.10.100			
		CER E (T018) E (T05)	-60 -60	+ 125 + 125	-60 -60	+ 125 + 125	-60	+ 125	-60	+ 125	°C °C °C
Operating	TA	EL	-60	+ 125	-60	+ 125					°C
		CER E (T018) E (T05)	-40 -40	+ 80 + 80	-40 -40	+ 80 + 80	-40	+ 80	-40	+ 80	•C •C •C
Soldering (10s)	т	EL (All)	-40	+ 80 250	-40	+ 80 250		250		250	°C
Coldering (108)	T _{sd}	(1711)	t	230	l	230	1	230	ł	230	1

¹ These are limiting values of operating and environmental conditions. Exceeding these values can cause damage to the device.

RCA Inc., Electro Optics

Electrical Characteristics

$(T_A = 25^{\circ}C, V_r = V_r (Typ.)$			C30618			C30619			C30641			C30642			UNITS
	Sym.	Pkg.	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	
Operating Voltage	Vr	(all)	0	5	10	0	5	10	0	2	5	0	2	5	V
Breakdown Voltage	Vb	(all)	20	40		20	40		20	30		15	25		V
Responsivity at 1300 nm	R _{1.3}	CER E (T018) E (T05) EL	.80 .78	.86 .84		.80 .78	.86 .84		.78	.84		.78	.84		A/W A/W A/W A/W
Responsivity at 1550 nm	R _{1.55}	CER E (T018) E (T05) EL	.85 .83	.90 .88		.85 .83	.90 .88		.83	.88		.83	.88		A/W A/W A/W
Dynamic Impedance	Z_d	(all)	25			5.0			1.0			.25			мΩ
Reverse Dark Current	I_d	(all)		2	10		5	20		20	100		100	500	nA
Noise Current ($f = 10 \text{ kHz}$, $\Delta f = 1.0 \text{ Hz}$)	I _n	(all)		.05	.25		.1	.5		.4	2.0		2.0	10.0	p A/Hz ^{1/2}
Capacitance	$ \begin{array}{c} C \\ V_r = V_r \\ V_r = 0 \end{array} $	(all) , (Typ)		4 12	6 18		8 20	10 25		40 100	50 125			150 300	pF pF
Rise / Fall	t, t	(all)		.3	1		1	3		2	6		6	15	ns
Chip Photosensitive Surface Shape Useful Area Useful Diameter		(all) (all) (all)	Circular .10 .35		Circular .20 .50		Circular .79 1.0			Circular 3.14 2.0			mm² mm		



Dimensions in millimeters. Dimensions in parentheses are in inches.

For further information, please contact your local RCA Electro Optics representative or RCA Inc., Electro Optics, P.O. Box 900, Vaudreuil, Canada J7V 7X3

Tel.: (514) 455-6191

Consistent with RCA Inc.'s policy of continually updating and improving its products, the type designation and data are subject to change, unless otherwise arranged. No obligations are assumed for notice of change of future manufacture of these devices or materials.

Trademark(s)* Registered Marca(s) Registrada(s). Information furnished by RCA is believed to be accurate and reliable. However, no responsibility is assumed by RCA for its use; nor for any infringements of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of RCA Inc. or its affiliates.

RCA Inc., Electro Optics

Printed in Canada

ED-0020/03/88